## NSN 5961-01-114-3481

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**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-114-3481 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **End Application:** An/apq-144 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to emitter voltage/static/base open and 450.0 collector to emitter voltage, dc with specified circuit between base and emitter and 9.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 15.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No